

M/A-COM Products

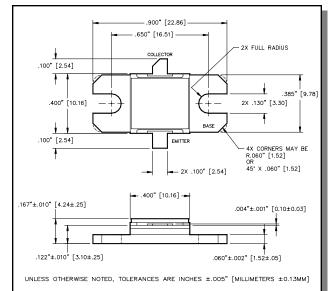
Released, 29 Jun 07

Radar Pulsed Power Transistor 8.5W, 2.7-2.9 GHz, 100µs Pulse, 10% Duty

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V _{CES}	65	V
Emitter-Base Voltage	V _{EBO}	3.0	V
Collector Current (Peak)	Ι _C	1.8	А
Power Dissipation @ +25°C	P _{TOT}	65	W
Storage Temperature	T _{STG}	-65 to +200	°C
Junction Temperature	TJ	200	°C

Electrical Specifications: T_c = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Мах	Units
Collector-Emitter Breakdown Voltage	I _C = 10mA		BV _{CES}	65	-	V
Collector-Emitter Leakage Current	V _{CE} = 40V		I _{CES}	-	1.5	mA
Thermal Resistance	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	R _{TH(JC)}	-	2.2	°C/W
Output Power	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	P _{OUT}	8.5	-	W
Power Gain	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	G _P	8.15	-	dB
Collector Efficiency	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	η _c	35	-	%
Pulse Droop	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	Droop	-	0.7	dB
Input Return Loss	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	RL	-	-6	dB
Load Mismatch Tolerance	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 36V, Pin = 1.3W	F = 2.7, 2.8, 2.9 GHz	VSWR-S	-	1.5:1	-

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PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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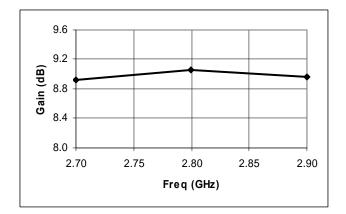


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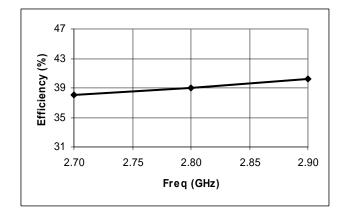
Typical RF Performance

Freq. (GHz)	Pin (W)	Pin (W)	Gain (dB)	lc (A)	Eff (%)	RL (dB)	Droop (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
2.7	1.3	10.2	8.92	0.74	38.0	-18.1	0.11	S	Р
2.8	1.3	10.5	9.06	0.75	39.1	-16.7	0.14	S	Р
2.9	1.3	10.3	8.97	0.71	40.3	-12.5	0.21	S	Р

Gain vs. Frequency

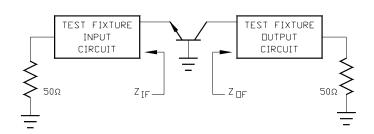


Collector Efficiency vs. Frequency



RF Test Fixture Impedance

F (GHz)	Z _{IF} (Ω)	Z _{OF} (Ω)
2.7	40 - j12	25 + j3.5
2.9	35 - j16	16 + j2.4
3.1	30 - j18	12 + j4.0



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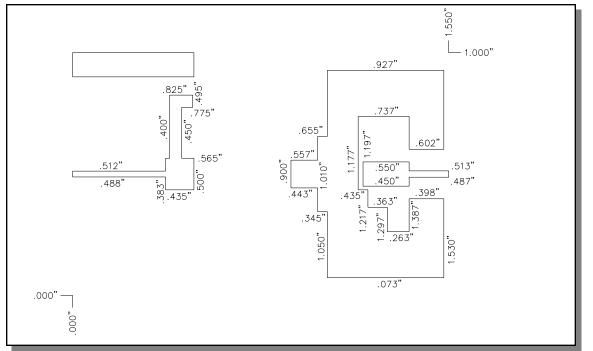
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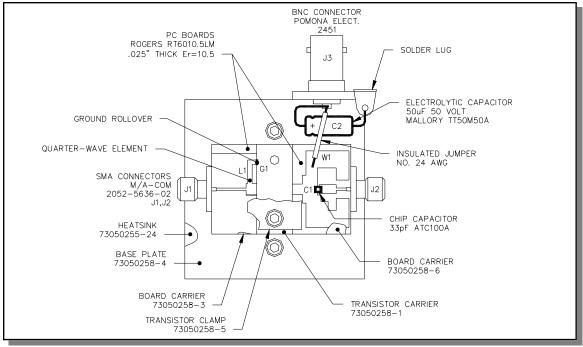
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Test Fixture Circuit Dimensions



Test Fixture Assembly



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